| A | | Reg. No. : | | | | | | | |
|-----|--|---|-----------|------------|------------|---------|-------|-------|-------|
| | | Question Pape | r Code | : 52003 | 3 | | | | |
| | B.E. / B. | Tech. DEGREE E2 | XAMIN | ATION, I | DEC 2 | 021 | | | |
| | | Second S | Semester | • | | | | | |
| | | Mechanical | Enginee | ring | | | | | |
| | | 15UPH203-MAT | • | • | 7 | | | | |
| | | | | | | | | | |
| | | (Common to Cher | | | 5) | | | | |
| | | (Regulati | on 2015 |) | | | | | |
| Dur | ation: Three hours | | | |] | Maxin | num: | 100 | Marks |
| | | PART A - (10 x | x = 10 | Marks) | | | | | |
| 1. | A dielectric can be made | a conductor by | | | | | | | CO1 |
| | (a) compression | (b) heating | (c) | doping | | | (d) f | reez | ing |
| 2. | Find the dielectric consta 4 | ant for a material with electric susceptibility o | | y of | f CO1 | | | | |
| | (a) 3 | (b)5 | (c)8 | 3 | | | (d)1 | 6 | |
| 3. | A semiconductor has temperature coefficient of resistance CO2- I | | | | | | | | |
| | (a) positive | | (b) | zero | | | | | |
| | (c) negative | | (d) | both pos | itive a | nd neg | ative | | |
| 4. | A hole in a semiconductor is defined as CO2 | | | | | CO2 | | | |
| | (a) a free electron (b) the incomplete part of an electron pair bon | | | | | ir bonc | | | |
| | (c) a free proton | () | d) a free | neutron | | | | | |
| 5. | The magnetic field which destroys the superconductivity is called CO3- | | | | | | | | |
| | (a) diamagnetic field (b) ferromagnetic field | | | | | | | | |
| | (c) ferrimagnetic field (d) critical field | | | | | | | | |
| 6. | The magnetic susceptibil | lity in a supercondu | uctor wil | l be | | | | | CO3 |
| | (a) postive | (b) negative | (c) | zero | | | (d) i | nfini | ty |
| 7. | When does metal transfo | orm into glass? | | | | | | | CO4 |
| | (a) at Curie temperature | | (b) | at Critica | ıl temp | eratur | e | | |
| | (c) at melting point of th | e metal | (d) | at glass t | ransiti | on tem | pera | ture | |

| 8. | Which of the following can be used to prepare nano-powder and nano- particles | | | | | CO4- R | |
|-----|--|---|--------------------------------------|-------------------------------|-----------------------|--------|--|
| | (a) sol | -gel technique | | (b) plasma arching | | | |
| | (c) CV | 'D | | (d) Electrodepostion | | | |
| 9. | Failure | e due to excessive de | | CO5- R | | | |
| | (a) yield strength (b) tensile strength | | | | | | |
| | (c) you | ing's modulus | | (d) all. | | | |
| 10. | Creep | Creep rate in ternary stage | | | | CO5 -R | |
| | | creases | (b) constant. | (c) increases | (d) none | | |
| | | | PART – B (5 x 2 | e= 10Marks) | | | |
| 11. | State Wiedemann Franz law. | | | | | CO1- R | |
| 12. | State Fermi level. | | | | CO2- R | | |
| 13. | What is Maglev? State its applications. | | | | CO3- R | | |
| 14. | What a | are carbon nanotube | s? | | CO4- R | | |
| 15. | State p | bath function. | | | | CO5 -R | |
| | | | PART – C (5 × | x 16= 80Marks) | | | |
| 16. | (a) | a) (i) Derive Claussius Mosotti relation. | | | CO1 -App | (10) | |
| | (ii) Write short notes on electrical and thermal conductivity. | | | | CO1- App | (6) | |
| | | | Or | | | | |
| | (b) (i) What do you know about Dielectric materials? | | | | CO1 -App | (4) | |
| | (ii) Write short notes on Electrical susceptibility, dielectric constant and polarization. | | | | | (12) | |
| 17. | (a) (i) Differentiate intrinsic and extrinsic semiconductor. | | | | | (6) | |
| | (ii) Evaluate various factors in hall effect | | | | CO2- App CO2 - App | | |
| | | | Or | | 11 | () | |
| | (b) | | er concentration level with temperat | derivation in detail and ure. | CO2- Ana | (16) | |
| 18. | (a) | (i) Explain in de applications. | tail High Tc sup | erconductors and list its | CO3 -Ana | (16) | |
| Or | | | | | | | |
| | (b) |) (i) Explain soft and hard magnets. | | | | (8) | |
| | (ii) Write short notes on SQUID and Domain theory | | | | CO3 -Ana | (8) | |
| | | | - | - | | | |

| 19. | (a) | (i) Explain plasma arcing in detail | CO4- U | (10) | | | |
|-----|-----|--|----------|------|--|--|--|
| | | (ii) Write short notes on ball milling | CO4 -U | (6) | | | |
| Or | | | | | | | |
| | (b) | (i) Explain in detail about metallic glasses preparation, properties and applications. | CO4 -Ana | (10) | | | |
| | | CO4- Ana | (6) | | | | |
| 20. | (a) | (i) Explain the mechanism of creep. | CO5 U | (10) | | | |
| | | (ii) Write short notes on carnot cycle. Or | CO5 U | (6) | | | |
| | (b) | CO5 U | (10) | | | | |
| | | CO5 U | (6) | | | | |

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